

Features

- Input voltage:1.5V~8V
- Output range:1.2V~5.0V
- Maximum output current: 400mA @ VOUT=3.3V
- PSRR: 60dB @1KHz

- Dropout voltage:180mV @ IOUT=100mA
- Quiescent current: 0.5µA Typ.
- Shut-down current: <1µA
- Recommend capacitor:1µF

• Built-in Short-Circuit Protection, Current Limiter

- Applications
- Radio control systems
- Cellphones, radiophone, digital cameras
- Bluetooth, wireless handsets
- Others portable consumer equipments

General Description

The HL55xx is a high accuracy, low noise, high speed CMOS Linear regulator with low power consumption and low dropout voltage, which provide large output currents even when the difference of the input-output voltage is small. The devices offer a new level of cost effective performance in cellular phones, laptop and notebook computers, and other portable

devices.

The current limiter's fold-back circuit also operates as a short circuit protection and an output current limiter at the output pin.

The HL55xx regulators are available in standard SOT23-3, SOT23-5 and DFN1*1-4 packages. Standard products are Pb-free and Halogen-free.

Selection Table

Part No.	Package	Temperature	Tape & Reel
HL55xxMR	SOT23-3	$-40 \sim +85^{\circ}C$	3000/REEL
HL55xxM5R	SOT23-5	-40 ~ +85 °C	3000/REEL
HL55xxFCR	DFN1*1-4	$-40 \sim +85^{\circ}C$	10000/REEL

Note: XX indicates 1.2V~5.0V by 0.1V step. For example, 28 means product outputs 2.8V

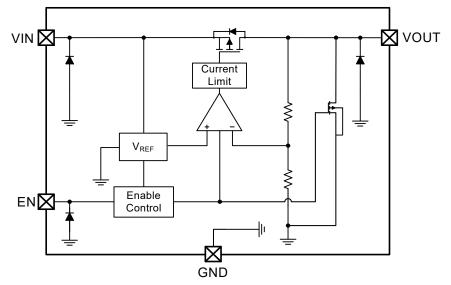
Order Information

HL55xx(12) (3)(4)(5)

Designator Symbo		Description
12	Integer	Output Voltage(1.2~5.0V)
	М	Package:SOT23-3
34	M5	Package:SOT23-5
	IntegerOutput Voltage(1.2~5.0V)MPackage:SOT23-3M5Package:SOT23-5FCPackage: DFN1*1-4RRoHS / Pb Free	Package: DFN1*1-4
E	R	RoHS / Pb Free
(5)	G	Halogen Free



Block Diagram



Pin Assignment

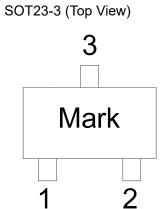
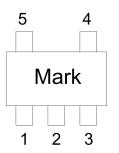


Table1: HL55xxMR series (SOT23-3 PKG)

PIN NO.	PIN NAME	FUNCTION			
1	GND	GND pin			
2	VOUT	Output voltage pin			
3	VIN	Input voltage pin			

Table2: HL55xxM5R series (SOT23-5 PKG)

SOT23-5 ((Top View)
00.200	(100 1101)



PIN NO	PIN NAME	FUNCTION
1	VIN	Input
2	GND	Ground
3	EN	Enable(Active high, not floating)
4	NC	Not connected
5	VOUT	Output



DFN1X1-4



: HL55xxFCR series (DFN1*1-4PKG)

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PIN NO	PIN NAME	FUNCTION
1	VOUT	Output
2	GND	Ground
3	EN	Enable(Active high, not floating)
4	VIN	Input



Absolute Maximum Ratings

Input Voltage	0.3V to 9V
Output Current	450mA
Operating Temperature	40℃ to 85℃

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

Thermal Information

Symbol	Parameter	Package	Max.	Unit
θ _{JA}		SOT23-3	500	°C/W
	Thermal Resistance (Junction to Ambient) (Assume no ambient airflow, no heat sink)	SOT23-5	500	
		DFN1*1-4	500	
		SOT23-3	0.40	
PD	Power Dissipation	SOT23-5	0.40	w
		DFN1*1-4	0.40	

Note: P_D is measured at Ta= 25 $^\circ\!\mathrm{C}$

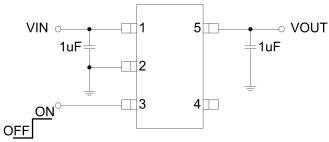
Electrical Characteristics

The following specifications apply for V_{OUT}=3.3V, T_A=25 $^\circ \rm C$, unless specified otherwise

SYMBOL	ITEMS	CONDITIONS	MIN	ТҮР	MAX	UNIT
VIN	Input Voltage		1.5		8	V
Vout	Output Range	Iout=1mA	-2	Vout	2	%
la	Quiescent Current	Vout=3.3V, lout=0		0.5		μA
Ілінт	Current Limit	V _{IN} =V _{EN} =4.5V		400		mA
M	Dreneut Valtare	V _{OUT} =3.3V, I _{OUT} =100mA		180		
V _{DROP}	Dropout Voltage	Vout=3.3V, lout=200mA 4	400		mV	
$\bigtriangleup V_{\text{LINE}}$	Line Regulation	V _{IN} =2.7~5.5V, I _{OUT} =1mA		0.01	0.15	%/V
$\bigtriangleup V_{\text{load}}$	Load Regulation	V _{OUT} =3.3V, I _{OUT} =1~300mA		200		mV
ISHORT	Short Current	$V_{EN}=V_{IN}, V_{OUT}$ Short to GND with 1 Ω		35		mA
I _{SHDN}	Shut-down Current	V _{EN} =0V			1	μA
PSRR	Power Supply Rejection Rate	V _{IN} =5V _{DC} +0.5V _{P-P} F=1KHz, I₀υτ=10mA		60		dB
V _{ENH}	EN logic high voltage	V _{IN} =5.5V, I _{OUT} =1mA	1.2		V _{IN}	V
VENL	EN logic low voltage	V _{IN} =5.5V, V _{OUT} =0V			0.4	V
I _{EN}	EN Input Current	V _{EN} = 0 to 5.5V			1	μA



Application Circuits

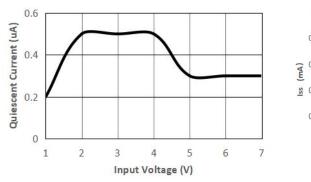


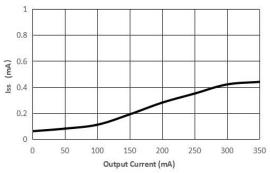
Typical Performance Characteristics

 $C_{\text{IN}}\text{=}1u\text{F},\,C_{\text{OUT}}\text{=}1u\text{F},\,V_{\text{IN}}\text{=}4.5\text{V},\,V_{\text{OUT}}\text{=}3.3\text{V}\text{ ,}\text{SOT23-5},T_{\text{A}}\text{=}25^{\circ}\text{C}$

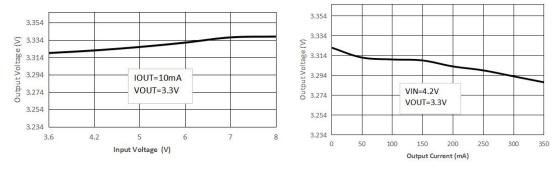
(Unless specified otherwise.Package:SOT23-5L)

(1) Quiescent current vs Input voltage

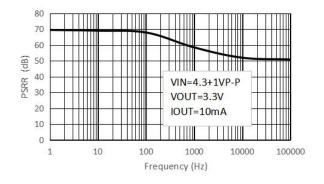




(2) Output Voltage vs Input voltage

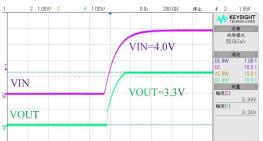


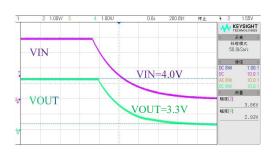
(3) PSRR vs Frequency





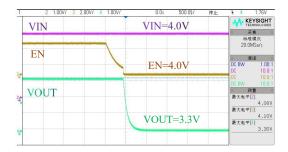
Power ON / OFF



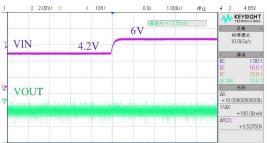


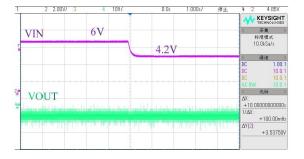
EN ON/OFF

VIN	VIN=4.0V	KEYSIGHT TECHNOLOGIES 采集
		标准模式 20.0MSa/s
EN	EN=4.0V	a 通道 DC BW 1.00: DC 10.0: DC 10.0:
	VOUT=3.3V	DC BW 100 副 一 一 一 一 一 一 一 一 一 一
VOUT		最大电平(3): 4.18) 最大电平(4): 3.42)

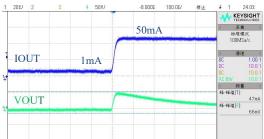


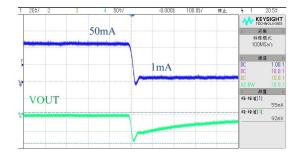
Line Transient





Load Transient







Application Information

In general, all the capacitors need to be low leakage. Any leakage the capacitors have will reduce efficiency, increase the quiescent current.

A recent trend in the design of portable devices has been to use ceramic capacitors to filter DC-DC converter inputs. Ceramic capacitors are often chosen because of their small size, low equivalent series resistance (ESR) and high RMS current capability. Also, recently, designers have been looking to ceramic capacitors due to shortages of tantalum capacitors.

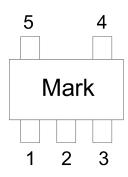
Unfortunately, using ceramic capacitors for input filtering can cause problems. Applying a voltage step to a ceramic capacitor causes a large current surge that stores energy in the inductance of the power leads. A large voltage spike is created when the stored energy is transferred from these inductance into the ceramic capacitor. These voltage spikes can easily be twice the amplitude of the input voltage step.

Many types of capacitors can be used for input bypassing, however, caution must be exercised when using multi layer ceramic capacitors (MLCC). Because of the self-resonant be generated under some start-up conditions, such as connecting the LDO input to a live power source.

The LDO also requires an output capacitor for loop stability. Connect a 1uF tantalum capacitor from OUT to GND close to the pins. For improved transient response, this output capacitor may be ceramic.



Marking Description



1) product code: 4

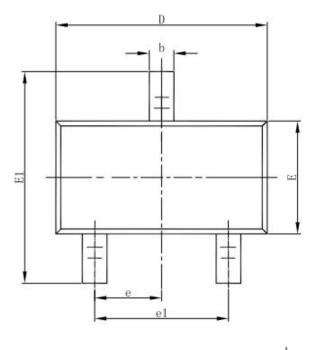
2 output voltage code:

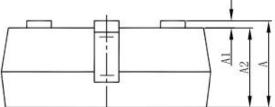
Symbol	Voltage(V)	Symbol	Voltage(V)	Symbol	Voltage(V)	Symbol	Voltage(V)
а	0.9	Α	3.5	n	2.2	N	4.8
b	1.0	В	3.6	0	2.3	0	4.9
С	1.1	С	3.7	Р	2.4	Р	5.0
d	1.2	D	3.8	q	2.5	Q	5.1
е	1.3	E	3.9	r	2.6	R	5.2
f	1.4	F	4.0	S	2.7	S	5.3
g	1.5	G	4.1	t	2.8	Т	5.4
h	1.6	Н	4.2	u	2.9	U	5.5
i	1.7	I	4.3	V	3.0	V	5.6
j	1.8	J	4.4	W	3.1	W	5.7
k	1.9	K	4.5	х	3.2	Х	5.8
	2.0	L	4.6	у	3.3	Y	5.9
m	2.1	М	4.7	Z	3.4	Z	6.0

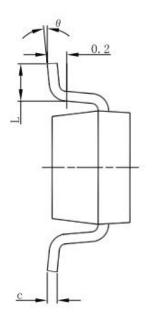
(3)(4): The last two of them are based on the time of this product which is the first time into production, the third is the year of this product first time into production, such as expressed in "1" in 2021, in "2" in 2022 and the forth is the mouth of this product first time into production, it can be in $1 \sim 9$, which is expressed in "0" in October, in November with an "A", in December with "B"; . For example: 4y16 represents HL5533M5R product is first put into production in June in 2021.



Package Information 3-pin SOT23-3 Outline Dimensions





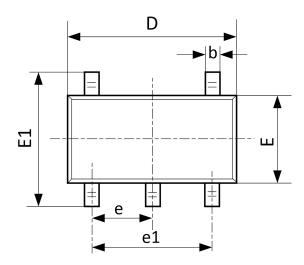


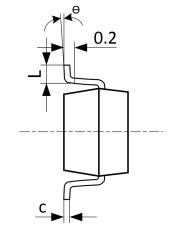
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

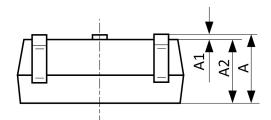


Ultra Low Current Consumption 400mA CMOS Voltage Regulator

SOT23-5 Outline Dimensions





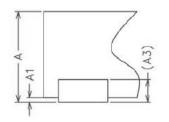


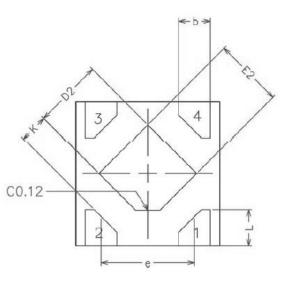
Gumbal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
e	0.950(BSC)		0.037(BSC)		
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°C	8°C	0°C	8℃	

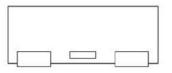


DFN1*1-4 Outline Dimensions









(UNITS	OF MEASL	JRE=MILLI	METER)		
SYMBOL	MIN	NOM	MAX		
А	0.34	0.37	0.40		
A1	0.00	0.02	0.05		
A3	0.100REF				
b	0.17	0.22	0.27		
D	0.95	1.00	1.05		
E	0.95	1.00	1.05		
D2	0.43	0.48	0.53		
E2	0.43	0.48	0.53		
L	0.20	0.25	0.30		
е	—	0.65	-		
K	0.15	-	-		

COMMON DIMENSIONS